SONY

ICX238AKE

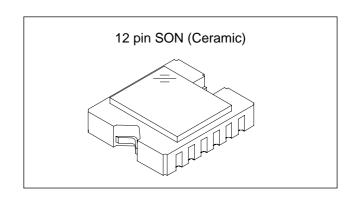
Diagonal 3mm (Type 1/6) CCD Image Sensor for NTSC Color Cameras

Description

The ICX238AKE is an interline CCD solid-state image sensor suitable for NTSC small color cameras. High resolution is achieved through the use of Ye, Cy, Mg, and G complementary color mosaic filters.

This chip features a field period readout system and an electronic shutter with variable charge-storage time.

The package is a small 12-pin SON(LCC).



Features

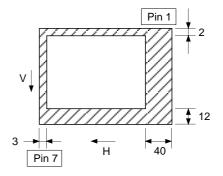
• High sensitivity and low smear

Horizontal register: 3.3 to 5.0V driveReset gate: 3.3 to 5.0V drive

No voltage adjustment

(Reset gate and substrate bias are not adjusted.)

- Low dark current and excellent antiblooming characteristics
- Continuous variable-speed shutter
- Recommended range of exit pupil distance: -10mm to $-\infty$
- Ye, Cy, Mg, and G complementary color mosaic filters on chip
- 12-pin ceramic SON(LCC) package



Optical black position (Top View)

Device Structure

• Interline CCD image sensor

• Image size: Diagonal 3mm (Type 1/6)

• Number of effective pixels: 768 (H) \times 494 (V) approx. 380K pixels • Total number of pixels: 811 (H) \times 508 (V) approx. 410K pixels

• Chip size: 3.30mm (H) \times 2.95mm (V) • Unit cell size: 3.200 μ m (H) \times 3.725 μ m (V)

Optical black: Horizontal (H) direction: Front 3 pixels, rear 40 pixels

Vertical (V) direction: Front 12 pixels, rear 2 pixels

• Number of dummy bits: Horizontal 22

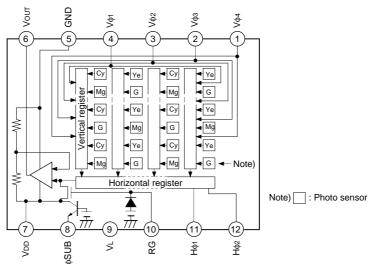
Vertical 1 (even fields only)

Substrate material:
 Silicon

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Block Diagram and Pin Configuration

(Top View)



Pin Description

| Pin No. | Symbol | Description | Pin No. | Symbol | Description |
|---------|--------|----------------------------------|---------|--------|------------------------------------|
| 1 | Vф4 | Vertical register transfer clock | 7 | VDD | Supply voltage |
| 2 | Vфз | Vertical register transfer clock | 8 | φSUB | Substrate clock |
| 3 | Vф2 | Vertical register transfer clock | 9 | VL | Protective transistor bias |
| 4 | Vф1 | Vertical register transfer clock | 10 | RG | Reset gate clock |
| 5 | GND | GND | 11 | Нф1 | Horizontal register transfer clock |
| 6 | Vouт | Signal output | 12 | Нф2 | Horizontal register transfer clock |

Absolute Maximum Ratings

| | Item | Ratings | Unit | Remarks |
|--------------------------|--|-------------|------|---------|
| | Vdd, Vout, RG – фSUB | -40 to +8 | V | |
| Against + CLID | Vφ1, Vφ3 – φSUB | -50 to +15 | V | |
| Against | Vφ2, Vφ4, VL – φSUB | -50 to +0.3 | V | |
| | Hφ1, Hφ2, GND – φSUB | -40 to +0.3 | V | |
| | Vdd, Vout, RG – GND | -0.3 to +20 | V | |
| Against GND | Vφ1, Vφ2, Vφ3, Vφ4 – GND | -10 to +18 | V | |
| | Hφ1, Hφ2 – GND | -10 to +6 | V | |
| Against V | Vφ1, Vφ3 – VL | -0.3 to +28 | V | |
| Against V∟ | Vφ2, Vφ4, Hφ1, Hφ2, GND – VL | -0.3 to +15 | V | |
| | Voltage difference between vertical clock input pins | to +15 | V | *1 |
| Between input clock pins | Ηφ1 — Ηφ2 | -6 to +6 | V | |
| Pino | Ηφ1, Ηφ2 – Vφ4 | -14 to +14 | V | |
| Storage temperature | | -30 to +80 | °C | |
| Operating temperature |) | -10 to +60 | °C | |

 $^{^{*1}\,}$ +24V (Max.) when clock width < 10µs, clock duty factor < 0.1%.

Bias Conditions

| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|----------------------------|--------|-------|------|-------|------|---------|
| Supply voltage | VDD | 14.55 | 15.0 | 15.45 | V | |
| Protective transistor bias | VL | | *1 | | | |
| Substrate clock | φSUB | | *2 | | | |
| Reset gate clock | φRG | | *2 | | | |

^{*1} VL setting is the VvL voltage of the vertical transfer clock waveform, or the same power supply as the VL power supply for the V driver should be used.

DC Characteristics

| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|----------------|--------|------|------|------|------|---------|
| Supply current | IDD | | 3.5 | 5.5 | mA | |

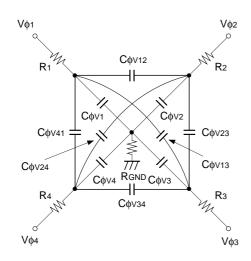
Clock Voltage Conditions

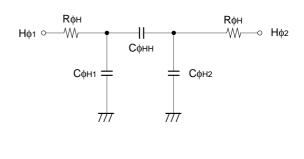
| Item | Symbol | Min. | Тур. | Max. | Unit | Waveform diagram | Remarks |
|-------------------------|---------------------------|-------|------|-------|------|------------------|--------------------------------------|
| Readout clock voltage | VvT | 14.55 | 15.0 | 15.45 | V | 1 | |
| | VvH1, VvH2 | -0.05 | 0 | 0.05 | V | 2 | VvH = (VvH1 + VvH2)/2 |
| | VvH3, VvH4 | -0.2 | 0 | 0.05 | V | 2 | |
| | VVL1, VVL2, VVL3, VVL4 | -8.0 | -7.5 | -7.0 | V | 2 | VvL = (VvL3 + VvL4)/2 |
| | Vφv | 6.8 | 7.5 | 8.05 | V | 2 | $V\phi V = VvHn - VvLn (n = 1 to 4)$ |
| Vertical transfer clock | VvH3 — VvH | -0.25 | | 0.1 | V | 2 | |
| voltage | VvH4 — VvH | -0.25 | | 0.1 | V | 2 | |
| | Vvhh | | | 0.3 | V | 2 | High-level coupling |
| | VvhL | | | 0.3 | V | 2 | High-level coupling |
| | Vvlh | | | 0.3 | V | 2 | Low-level coupling |
| | VVLL | | | 0.3 | V | 2 | Low-level coupling |
| Horizontal transfer | Vфн | 3.0 | 3.3 | 5.25 | V | 3 | |
| clock voltage | VHL | -0.05 | 0 | 0.05 | V | 3 | |
| Reset gate clock | Vþrg | 3.0 | 3.3 | 5.5 | V | 4 | Input through 0.1µF capacitance |
| voltage | VRGLH - VRGLL | | | 0.4 | V | 4 | Low-level coupling |
| | VRGL - VRGLm | | | 0.5 | V | 4 | Low-level coupling |
| Substrate clock voltage | Vфѕив | 21.5 | 22.5 | 23.5 | V | 5 | |

^{*2} Do not apply a DC bias to the substrate clock and reset gate clock pins, because a DC bias is generated within the CCD.

Clock Equivalent Circuit Constant

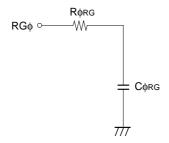
| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|---|----------------|------|------|------|------|---------|
| Capacitance between vertical transfer | Сф∨1, Сф∨3 | | 680 | | pF | |
| clock and GND | Сф∨2, Сф∨4 | | 220 | | pF | |
| | СфV12, СфV34 | | 91 | | pF | |
| Capacitance between vertical transfer clocks | Сф∨23, Сф∨41 | | 75 | | pF | |
| Sidesite | СфV13, СфV24 | | 30 | | pF | |
| Capacitance between horizontal transfer clock and GND | Сфн1, Сфн2 | | 13 | | pF | |
| Capacitance between horizontal transfer clocks | Сфнн | | 34 | | pF | |
| Capacitance between reset gate clock and GND | Сфяс | | 5 | | pF | |
| Capacitance between substrate clock and GND | Сфѕив | | 180 | | pF | |
| Vertical transfer clock series resistor | R1, R2, R3, R4 | | 120 | | Ω | |
| Vertical transfer clock ground resistor | RGND | | 15 | | Ω | |
| Horizontal transfer clock series resistor | Rфн | | 15 | | Ω | |
| Reset gate clock series resistor | Rørg | | 51 | | Ω | |





Vertical transfer clock equivalent circuit

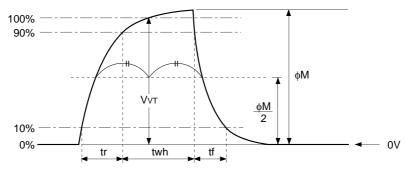
Horizontal transfer clock equivalent circuit



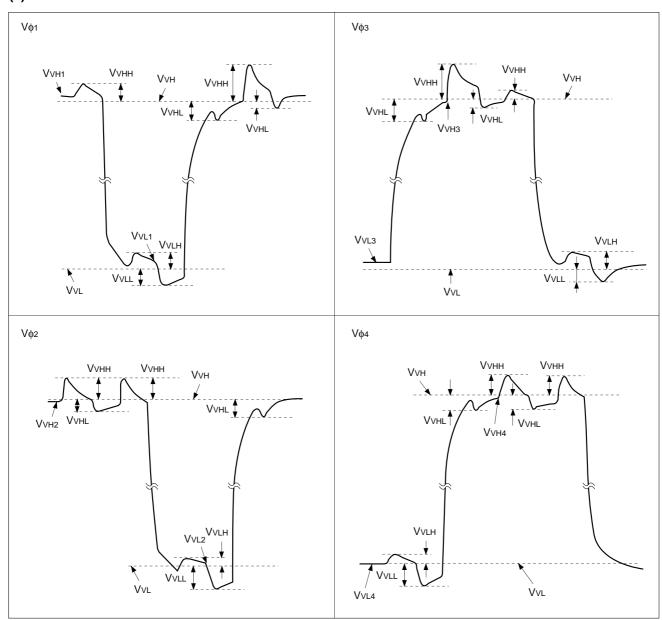
Reset gate clock equivalent circuit

Drive Clock Waveform Conditions

(1) Readout clock waveform



(2) Vertical transfer clock waveform

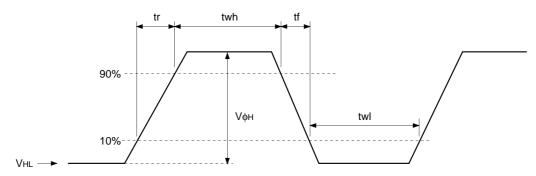


 $V_{VH} = (V_{VH1} + V_{VH2})/2$

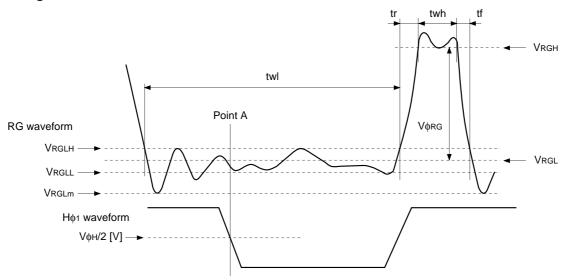
 $V \lor L = (V \lor L3 + V \lor L4)/2$

 $V\phi V = VVHN - VVLN (n = 1 to 4)$

(3) Horizontal transfer clock waveform



(4) Reset gate clock waveform



VRGLH is the maximum value and VRGLL is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG. In addition, VRGL is the average value of VRGLH and VRGLL.

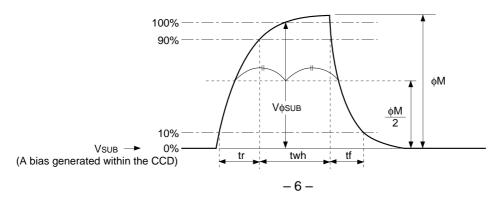
$$V_{RGL} = (V_{RGLH} + V_{RGLL})/2$$

Assuming VRGH is the minimum value during the interval twh, then:

$$V \phi RG = V RGH - V RGL$$

Negative overshoot level during the falling edge of RG is VRGLm.

(5) Substrate clock waveform



Clock Switching Characteristics

| | Item | Symbol | | twh | | | twl | | | tr | | | tf | | Unit | Remarks |
|------------------------------|------------------------|-----------------------|------|------|------|------|------|------|------|------|------|------|------|------|-------|---------------------|
| | пеш | Symbol | Min. | Тур. | Мах. | Offic | Remarks |
| Rea | dout clock | VT | 2.3 | 2.5 | | | | | | 0.5 | | | 0.5 | | μs | During readout |
| Vert | tical transfer k | Vφ1, Vφ2, Vφ3, Vφ4 | | | | | | | | | | 15 | | 250 | ns | *1 |
| =Ş | During | Нф1 | 26 | 28.5 | | 26 | 28.5 | | | 6.5 | 9.5 | | 6.5 | 9.5 | ns | *2 |
| Horizontal transfer clock | imaging | Нф2 | 26 | 28.5 | | 26 | 28.5 | | | 6.5 | 9.5 | | 6.5 | 9.5 | 113 | |
| loriz nsfe | During parallel-serial | Нф1 | | 5.38 | | | | | | 0.01 | | | 0.01 | | 116 | |
| tra | conversion | Нф2 | | | | | 5.38 | | | 0.01 | | | 0.01 | | μs | |
| Res | et gate clock | фRG | 11 | 13 | | | 51 | | | 3 | | | 3 | | ns | |
| Sub | strate clock | фѕив | 1.5 | 1.8 | | | | | | | 0.5 | | | 0.5 | μs | During drain charge |

^{*1} When vertical transfer clock driver CXD1267AN is used.

^{*2} When $V\phi H = 3.0V$. If $\geq tr - 2ns$, and the cross-point voltage (VcR) for the H $\phi 1$ rising side of the H $\phi 1$ and H $\phi 2$ waveforms must be at least $V\phi H/2$ [V].

| Item | Symbol | | two | | Unit | Remarks |
|---------------------------|--------------------------|------|------|------|-------|----------|
| item | Gyllibol | Min. | Тур. | Max. | Offic | IXemaiks |
| Horizontal transfer clock | Н ф1, Н ф2 | 22 | 26 | | ns | *3 |

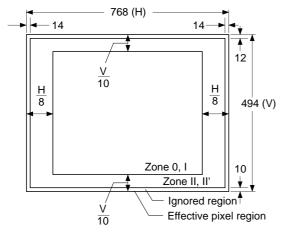
^{*3} The overlap period for twh and twl of horizontal transfer clocks $H\phi_1$ and $H\phi_2$ is two.

Image Sensor Characteristics

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Min. | Тур. | Max. | Unit | Measurement method | Remarks |
|--------------------------|--------|------|-------|-------|------|--------------------|---------------|
| Sensitivity | S | 240 | 300 | | mV | 1 | |
| Sensitivity ratio | RмgG | 0.93 | | 1.35 | | 2 | |
| Sensitivity ratio | RYeCy | 1.15 | | 1.48 | | 2 | |
| Saturation signal | Ysat | 600 | | | mV | 3 | Ta = 60°C |
| Smear | Sm | | 0.009 | 0.015 | % | 4 | |
| Video signal sheding | OL Iv | | | 20 | % | 5 | Zone 0 and I |
| Video signal shading | SHy | | | 25 | % | 5 | Zone 0 to II' |
| Uniformity between video | ΔSr | | | 10 | % | 6 | |
| signal channels | ΔSb | | | 10 | % | 6 | |
| Dark signal | Ydt | | | 2 | mV | 7 | Ta = 60°C |
| Flicker Y | Fy | | | 2 | % | 8 | |
| Flicker R-Y | Fcr | | | 5 | % | 8 | |
| Flicker B-Y | Fcb | | | 5 | % | 8 | |
| Line crawl R | Lcr | | | 3 | % | 9 | |
| Line crawl G | Lcg | | | 3 | % | 9 | |
| Line crawl B | Lcb | | | 3 | % | 9 | |
| Line crawl W | Lcw | | | 3 | % | 9 | |

Zone Definition of Video Signal Shading



Measurement System

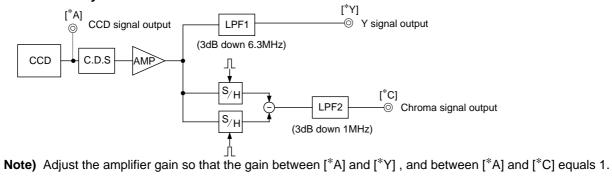
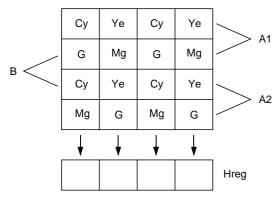


Image Sensor Characteristics Measurement Method

Measurement conditions

- 1) In the following measurements, the device drive conditions are at the typical values of the bias and clock voltage conditions.
- 2) In the following measurements, spot blemishes are excluded and, unless otherwise specified, the optical black level (OB) is used as the reference for the signal output, which is taken as the value of Y signal output or chroma signal output of the measurement system.

Color coding of this image sensor & Composition of luminance (Y) and chroma (color difference) signals



As shown in the left figure, fields are read out. The charge is mixed by pairs such as A1 and A2 in the A field. (pairs such as B in the B field)

As a result, the sequence of charges output as signals from the horizontal shift register (Hreg) is, for line A1, (G + Cy), (Mg + Ye), (G + Cy), and (Mg + Ye).

Color Coding Diagram

These signals are processed to form the Y signal and chroma (color difference) signal. The Y signal is formed by adding adjacent signals, and the chroma signal is formed by subtracting adjacent signals. In other words, the approximation:

$$Y = \{(G + Cy) + (Mg + Ye)\} \times 1/2$$

= 1/2 {2B + 3G + 2R}

is used for the Y signal, and the approximation:

$$R - Y = \{(Mg + Ye) - (G + Cy)\}\$$

= $\{2R - G\}$

is used for the chroma (color difference) signal. For line A2, the signals output from Hreg in sequence are

$$(Mg + Cy), (G + Ye), (Mg + Cy), (G + Ye).$$

The Y signal is formed from these signals as follows:

$$Y = \{(G + Ye) + (Mg + Cy)\} \times 1/2$$

= 1/2 {2B + 3G + 2R}

This is balanced since it is formed in the same way as for line A1.

In a like manner, the chroma (color difference) signal is approximated as follows:

$$-(B-Y) = \{(G + Ye) - (Mg + Cy)\}\$$

= $-\{2B-G\}$

In other words, the chroma signal can be retrieved according to the sequence of lines from R - Y and - (B - Y) in alternation. This is also true for the B field.

Definition of standard imaging conditions

1) Standard imaging condition I:

Use a pattern box (luminance 706cd/m², color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter and image at F5.6. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

2) Standard imaging condition II:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

3) Standard imaging condition III:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens (exit pupil distance –33mm) with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. Sensitivity

Set to standard imaging condition I. After selecting the electronic shutter mode with a shutter speed of 1/250s, measure the Y signal (Ys) at the center of the screen and substitute the value into the following formula.

$$S = Ys \times \frac{250}{60} [mV]$$

2. Sensitivity ratio

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then measure the Mg signal output (S_{Mg} [mV]) and G signal output (S_{G} [mV]), and Ye signal output (S_{Ye} [mV]) and Cy signal output (S_{Cy} [mV]) at the center of the screen with frame readout method. Substitute the values into the following formula.

$$R_{MgG} = S_{Mg}/S_{G}$$

 $R_{YeCy} = S_{Ye}/S_{Cy}$

3. Saturation signal

Set to standard imaging condition II. After adjusting the luminous intensity to 10 times the intensity with average value of the Y signal output, 200mV, measure the minimum value of the Y signal.

4. Smear

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity to 500 times the intensity with average value of the Y signal output, 200mV. When the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value YSm [mV] of the Y signal output and substitute the value into the following formula.

$$Sm = \frac{YSm}{200} \times \frac{1}{500} \times \frac{1}{10} \times 100 \text{ [\%] (1/10V method conversion value)}$$

5. Video signal shading

Set to standard imaging condition III. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity so that the average value of the Y signal output is 200mV. Then measure the maximum (Ymax [mV]) and minimum (Ymin [mV]) values of the Y signal and substitute the values into the following formula.

$$SHy = (Ymax - Ymin)/200 \times 100 [\%]$$

6. Uniformity between video signal channels

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then measure the maximum (Crmax, Cbmax [mV]) and minimum (Crmin, Cbmin [mV]) values of the R - Y and B - Y channels of the chroma signal and substitute the values into the following formula.

$$\Delta Sr = | (Crmax - Crmin)/200 | \times 100 [\%]$$

 $\Delta Sb = | (Cbmax - Cbmin)/200 | \times 100 [\%]$

7. Dark signal

Measure the average value of the Y signal output (Ydt [mV]) with the device ambient temperature 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

8. Flicker

1) Fy

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then measure the difference in the signal level between fields (Δ Yf [mV]). Then substitute the value into the following formula.

$$Fy = (\Delta Yf/200) \times 100 [\%]$$

2) Fcr, Fcb

Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, insert an R or B filter, and then measure both the difference in the signal level between fields of the chroma signal (Δ Cr, Δ Cb) as well as the average value of the chroma signal output (CAr, CAb). Substitute the values into the following formula.

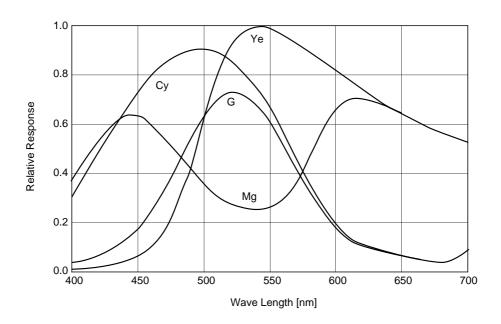
Fci =
$$(\Delta \text{Ci/CAi}) \times 100 \, [\%] \, (i = r, b)$$

9. Line crawls

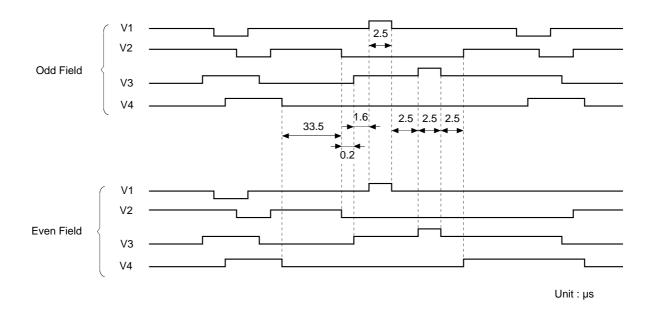
Set to standard imaging condition II. Adjust the luminous intensity so that the average value of the Y signal output is 200mV, and then insert a white subject and R, G, and B filters and measure the difference between Y signal lines for the same field (Δ Ylw, Δ Ylr, Δ Ylg, Δ Ylb [mV]). Substitute the values into the following formula.

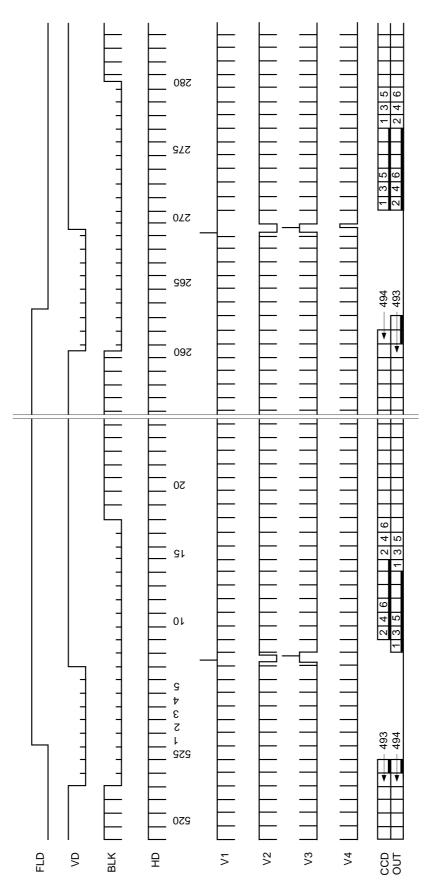
Lci =
$$(\Delta Y li/200) \times 100 [\%]$$
 (i = w, r, g, b)

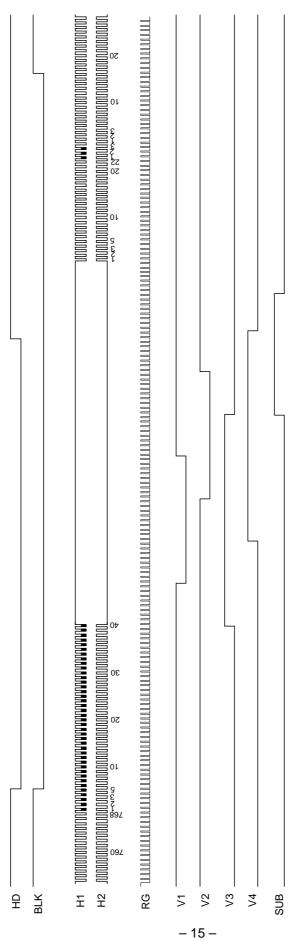
Spectral Sensitivity Characteristics (excludes both lens characteristics and light source characteristics)



Sensor Readout Clock Timing Chart







Notes on Handling

1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

- a) Either handle bare handed or use non-chargeable gloves, clothes or material.
 - Also use conductive shoes.
- b) When handling directly use an earth band.
- c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- d) Ionized air is recommended for discharge when handling CCD image sensor.
- e) For the shipment of mounted substrates, use boxes treated for the prevention of static charges.

2) Soldering

- a) Make sure the upper surface of ceramic package temperature does not exceed 80°C.
- b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a ground 30W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.
- c) To dismount an image sensor, do not use a solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero cross On/Off type and connect it to ground.

3) Dust and dirt protection

Image sensors are packed and delivered by taking care of protecting its glass plates from harmful dust and dirt. Clean glass plates with the following operation as required, and use them.

- a) Perform all assembly operations in a clean room (class 1000 or less).
- b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
- c) Clean with a cotton bud and ethyl alcohol if the grease stained. Be careful not to scratch the glass.
- d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.

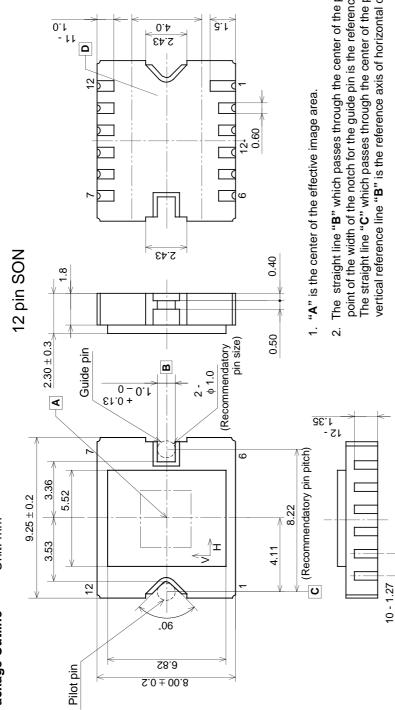
4) Installing (attaching)

- a) If a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the bottom of the package. Therefore, for installation, use either an elastic load, such as a spring plate, or an adhesive.
- b) The adhesive may cause the marking on the rear surface to disappear.
- c) If the metal, etc., clash or rub against the package, the dust may be generated by the fragments of package.
- d) Acrylate anaerobic adhesives are generally used to attach CCD image sensors. In addition, cyanoacrylate instantaneous adhesives are sometimes used jointly with acrylate anaerobic adhesives. (reference)

5) Others

- a) Do not expose to strong light (sun rays) for long periods, color filters will be discolored. When high luminance objects are imaged with the exposure level control by electronic-iris, the luminance of the image-plane may become excessive and discolor of the color filter will possibly be accelerated. In such a case, it is advisable that taking-lens with the automatic-iris and closing of the shutter during the power-off mode should be properly arranged. For continuous using under cruel condition exceeding the normal using condition, consult our company.
- b) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.

Unit: mm Package Outline



point of the width of the notch for the guide pin is the reference axis of vertical direction (V). The straight line "C" which passes through the center of the pilot pin at right angle to The straight line "B" which passes through the center of the pilot pin and the middle vertical reference line "B" is the reference axis of horizontal direction (H)

The bottom "D" of the package is the height reference.

4 . The center of the effective image area, relative to"B" and "C" is $(H, V) = (4.11, 0) \pm 0.15mm$. 5 . The rotation angle of the effective image area relative to the line "B" is \pm 1 $^{\circ}$.

6 . The height from the bottom "**D**" to the effective image area is 1.03 ± 0.15 mm.

The tilt of the effective image area relative to the bottom "D" is less than 25μm.

8. The thickness of the cover glass is 0.5mm, and the refractive index is 1.5.

9. Notches for the pilot pin and the guide pin must not be used for fixing.

10. The upside of the ceramic package must not be used for the area of reference or adapting parts because of extra seal resin on it.

PACKAGE STRUCTURE

| PACKAGE MATERIAL | Ceramic |
|------------------|--------------|
| LEAD TREATMENT | GOLD PLATING |
| LEAD MATERIAL | |
| PACKAGE MASS | 0.44g |
| DRAWING NUMBER | AS-F3-02(E) |